

E-MRS Announces Nominees for Board of Delegates

The European Materials Research Society has announced a slate of nominees to be Group I members of the E-MRS Board of Delegates. According to E-MRS legal statutes, the Board of Delegates is composed of two types of representatives: (I) a maximum of 50 elected members, and (II)—to achieve an equilibrium representation among fields of activity and European nations—10 supplementary members proposed by the Executive Committee and subsequently approved by the Board of Delegates. Ballots are still available from E-MRS President P. Siffert at the address on p. 2 in this issue. Group I nominees include:

Dr. M. von Allmen, Cendres Metaux S.A., Biel, Switzerland (metallurgy)

Prof. Dr. C.A.J. Ammerlaan, Natuurkundig Laboratorium, Universiteit, Amsterdam, Netherlands (properties of semiconductors)

Prof. Dr. M. Balkanski, Laboratoire de Physique des Solides, Université Pierre et Marie Curie, Paris, France (spectroscopy of solids, atomic motion of solids)

Prof. Dr. A. Barbedo de Magalhaes, Departamento de Engenharia Mecânica, Universidade, Porto, Portugal (cast iron metallurgy, composites)

Prof. Dr. G. Battaglin, Dipartimento di Chimica Fisica, Università, Venezia, Italy (characterization of materials)

Prof. Dr. G.G. Bentini, Istituto LAMEL, Consiglio Nazionale delle Ricerche, Bologna, Italy (characterization of materials)

Dr. P.F. Bongers, Philips Research Laboratories, Philips, Eindhoven, Netherlands (chemistry of solids)

Dr. I.W. Boyd, Department of Electronic and Electrical Engineering, University College, London, United Kingdom (laser processing of semiconducting materials)

Prof. Dr. S.U. Campisano, Dipartimento di Fisica, Università, Catania, Italy (beam interactions with materials)

Prof. Dr. G.A. Chadwick, Hi-Tec Metals R&D Ltd. and Engineering Materials, University, Southampton, United Kingdom (metallurgy and materials sciences)

Dr. G. Crean, National Microelectronics Research Centre, University College, Cork, Ireland (semiconducting materials and measurement sciences)

Dr. A.G. Cullis, Royal Signals and Radar Establishment, Malvern, United Kingdom (beam processing of materials and electron microscopy)

Prof. Dr. I. Eisele, Fakultät für Elektrotechnik, Universität der Bundeswehr München, Neubiberg, West Germany (molecular beam epitaxy)

Dr. E. Fogarassy, Centre de Recherches Nucléaires, PHASE, Strasbourg, France

(photochemistry)

Prof. Dr. C. Fotakis, Research Center of Crete, Foundation for Research and Technology - Hellas, Heraklio, Crete, Greece (photo-assisted processing of materials)

Prof. Dr. H. Fredriksson, Department of Casting of Metals, The Royal Institute of Technology, Stockholm, Sweden (casting of metals)

Dipl. Phys. P. Glasow, Deputy Director, Forschungslaboratorien, Siemens AG, Erlangen, West Germany (sensors, high-temperature electronic devices)

Dr. A. Golanski, Centre National d'Études des Télécommunications, Grenoble, France (beam processing of semiconductors)

Dr. F. Greuter, Corporate Research, Asea Brown Boveri, Baden-Dättwil, Switzerland (electronic structure of solid surfaces, superconductors)

Dr. N. Hoey-Petersen, Vice President, Norsk Hydro a.s., Oslo, Norway (materials sciences: health, safety, environment)

Prof. Dr. J.T.M. de Hosson, Department of Applied Physics, University, Groningen, Netherlands (properties and defects in metals and ceramics)

Dr. S. Kalbitzer, Department of Nuclear Solid State Physics, Max-Planck-Institut für Kernphysik, Heidelberg, West Germany (ion beam processing and analysis of semiconducting materials)

Prof. Dr. G. Kostorz, Institut für Angewandte Physik, Eidgenössische Technische Hochschule, Zürich, Switzerland (plasticity and microstructure of alloys)

Prof. Dr. E.F. Krimmel, Institut für Kernphysik, Johann Wolfgang, Goethe-Universität, Frankfurt/Main, West Germany (beam processing of materials)

Prof. Dr. G. Landwehr, Physikalisches Institut, Universität Würzburg, West Germany (semiconductor properties in high magnetic fields, two-dimensional systems)

Prof. Dr. L.D. Laude, Laboratoire de Physique de l'Etat Solide, Université de l'Etat, Mons, Belgium (physics of surfaces, laser processing of materials)

Dr. J.F. McGilp, Director, Department of the Science of Materials, Trinity College, Dublin, Ireland (metal-semiconductor interfaces)

Prof. Dr. J.P. Mercier, Laboratoire de Physique et de Chimie des Haute Polymères, Université Catholique de Louvain, Louvain, Belgium (physics and chemistry of polymers)

Dr. S. Moya, Instituto de Cerámica y Vidrio, C.S.I.C., Arganda del Rey, Spain (ceramic materials)

Dr. D. Muster, Laboratoire d'Étude, d'Évaluation et de Développement de Bioma-

teriaux, Strasbourg, France (biomaterials)

Dr. V.T. Nguyen, Centre National d'Études des Télécommunications Grenoble, Meylan, France (beam-assisted electronic device technology)

Prof. Dr. D. Nobili, Dipartimento di Chimica Applicata e Scienza dei Materiali, Università, Bologna, Italy (nuclear fuels, cladding materials)

Prof. Dr. M. Peroz-Amor, Physics Department, University of Santiago, Vigo, Spain (laser processing of materials)

Dr. S.D. Peteves, Ceramics-Materials Division, Joint Research Centre, Petten, Netherlands (advanced ceramics)

Prof. Dr. P. Pinard, Laboratoire de Physique de la Matière, CNRS-INSA-Lyon, Villeurbanne, France (photovoltaic and components for microelectronics)

Dr. K.J. Reeson, Department of Electronic and Electrical Engineering, University, Guildford Surrey, United Kingdom (ion beam synthesis of materials)

Prof. Dr. C. Rissuto, Director, Consorzio Interuniversitario Nazionale per la Fisica della Materia, Genova, Italy (superconductivity, magnetism)

Dr. M. Rodot, Laboratoire de Physique des Solides, CNRS, Meudon, France (semiconductor materials)

Prof. Dr. J.M. Serratos, Instituto de Cienola de Materiales, Consejo Superior de Investigaciones Científicas, Madrid, Spain (crystallochemistry, surface properties of oxides)

Prof. Dr. P. Siffert, Centre de Recherches Nucléaires, PHASE, Strasbourg, France (chemistry and physics of beam technologies)

Prof. Dr. J.C. Soares, Centro de Física Nuclear, Universidade, Lisboa, Portugal (nuclear solid state physics)

Prof. Dr. B. Stritzker, Institut für Schichten-und Ionentechnik, Kernforschungsanlage, Jülich, West Germany (beam processing of ceramics, metals, and superconductors)

Dr. J. Torres, Centre National d'Études des Télécommunications, Meylan, France (thin films and thin film interfaces)

Prof. Dr. M. Van de Voorde, Materials Division, Joint Research Centre, Petten, Netherlands (materials science)

Dr. C. Wippler, Ecole d'Application des Hauts Polymères, Université Louis Pasteur, Strasbourg, France (chemistry of polymers)

Dr. L. Zanotti, Director, Istituto Materiali Speciali per Elettronica e Magnetismo, Consiglio Nazionale delle Ricerche, Parma, Italy (compounds, magnets, oxides) □